

The graph displays the relationship between Drain-Source Current (I_{DS}) and Drain-Source Voltage (V_{DS}) for a MOSFET at various gate-source voltages (V_{GS}). The x-axis represents V_{DS} in Volts (V), ranging from 0 to 60. The y-axis represents I_{DS} in microamperes (μA), ranging from 0 to 1000. The curves are labeled with their corresponding V_{GS} values: 0.0 V, -2.0 V, -4.0 V, -6.0 V, -8.0 V, -10.0 V, -12.0 V, and -14.0 V. The curves show that I_{DS} increases with V_{DS} and is higher for more negative V_{GS} values.

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